
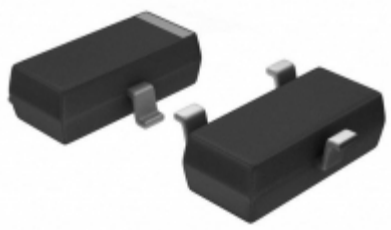







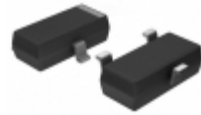


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|---|--|
|  | <h2 style="color: red;">FJV3112RMTF</h2> |
| | <p>Hersteller-Teilenummer: FJV3112RMTF</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS NPN 200MW SOT23-3</p> <p>Datenblätter: 1.FJV3112RMTF.pdf 2.FJV3112RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 41500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|---|
| Teilenummer | FJV3112RMTF |
| Hersteller | Fairchild/ON Semiconductor |
| Beschreibung | TRANS PREBIAS NPN 200MW SOT23-3 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-Bipolar |
| Teilstatus | 41500 pcs Stock |
| Serie | - |
| Befestigungsart | Surface Mount |
| Leistung - max | 200mW |
| Verpackung / Gehäuse | TO-236-3, SC-59, SOT-23-3 |
| Supplier Device-Gehäuse | SOT-23-3 (TO-236) |
| Transistor-Typ | NPN - Pre-Biased |
| Strom - Kollektor (Ic) (max) | 100mA |
| Spannung - Kollektor-Emitter-Durchbruch (max) | 40V |
| VCE Sättigung (Max) @ Ib, Ic | 300mV @ 1mA, 10mA |
| Strom - Collector Cutoff (Max) | 100nA (ICBO) |
| DC Stromgewinn (HFE) (Min) @ Ic, VCE | 100 @ 1mA, 5V |
| Frequenz - Übergang | 250MHz |
| Widerstand - Base (R1) (Ohm) | 47k |
| Widerstand - Emitter-Basis (R2) (Ohm) | - |
| Verpackung | Tape & Reel (TR) |

FJV3112RMTF ist neu im Original, Suche FJV3112RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3112RMTF Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3112RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|---|--|
|  <p>FJV3111RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |  <p>FJV3114RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |  <p>FJV3110RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |  <p>FJV3111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |
|  <p>FJV3114RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |  <p>FJV3113RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |  <p>FJV3113RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |  <p>FJV3115RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p> |

heiße Teile

Mehr

| | | | | |
|---|---|---|--|---|
|  FJV3101RLIMTF |  FJV3101RMTF |  FJV3101RMTF |  FJV3102RMTF |  FJV3102RMTF |
|  FJV3103RMTF |  FJV3103RMTF |  FJV3104RMTF |  FJV3104RMTF |  FJV3105RMTF |
|  FJV3105RMTF |  FJV3106RMTF |  FJV3106RMTF |  FJV3107RMTF |  FJV3107RMTF |
|  FJV3108RMTF |  FJV3108RMTF |  FJV3109R |  FJV3109RMTF |  FJV3109RMTF |
|  FJV3110RMTF |  FJV3110RMTF |  FJV3111RMTF |  FJV3111RMTF |  FJV3112RMTF |
|  FJV3113RMTF |  FJV3113RMTF |  FJV3114RMTF |  FJV3114RMTF |  FJV3115RMTF |
|  FJV3115RMTF |  FJV4101RMTF |  FJV4101RMTF |  FJV4102RLIMTF |  FJV4102RMTF |
|  FJV4102RMTF |  FJV4103RMTF |  FJV4103RMTF |  FJV4104RMTF |  FJV4104RMTF |
|  FJV4105RMTF |  FJV4105RMTF |  FJV4106RMTF |  FJV4106RMTF |  FJV4107RMTF |
|  FJV4107RMTF |  FJV4108RMTF |  FJV4108RMTF |  FJV4109RMTF |  FJV4109RMTF |

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